

Silicon PNP Epitaxial Planar Transistor (Complement to type 2SC3264)

Application : Audio and General

Absolute maximum ratings (Ta=25°C)

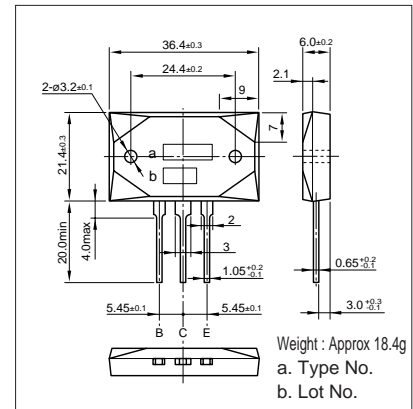
Symbol	2SA1295	Unit
V _{CB0}	-230	V
V _{CEO}	-230	V
V _{EB0}	-5	V
I _C	-17	A
I _B	-5	A
P _C	200(T _C =25°C)	W
T _J	150	°C
T _{stg}	-55 to +150	°C

Electrical Characteristics (Ta=25°C)

Symbol	Conditions	2SA1295	Unit
I _{CB0}	V _{CB} =-230V	-100max	μA
I _{EB0}	V _{EB} =-5V	-100max	μA
V(BR) _{CEO}	I _C =-25mA	-230min	V
h _{FE}	V _{CE} =-4V, I _C =-5A	50min*	
V _{CE(sat)}	I _C =-5A, I _B =-0.5A	-2.0max	V
f _T	V _{CE} =-12V, I _E =2A	35typ	MHz
C _{OB}	V _{CB} =-10V, f=1MHz	500typ	pF

*h_{FE} Rank O(50to100), Y(70to140)

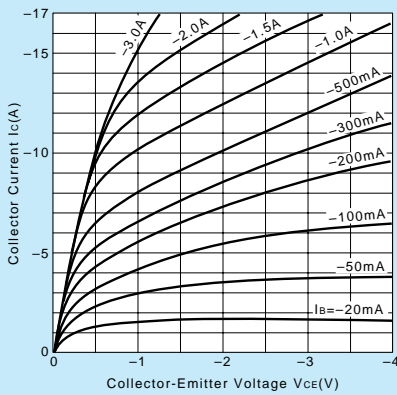
External Dimensions MT-200



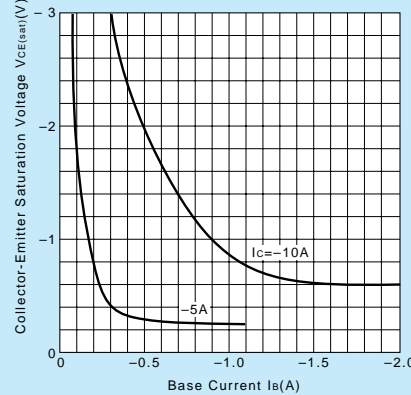
Typical Switching Characteristics (Common Emitter)

V _{CC} (V)	R _L (Ω)	I _C (A)	V _{BB1} (V)	V _{BB2} (V)	I _{B1} (mA)	I _{B2} (mA)	t _{on} (μs)	t _{stg} (μs)	t _f (μs)
-60	12	-5	-10	5	-500	500	0.35typ	1.50typ	0.30typ

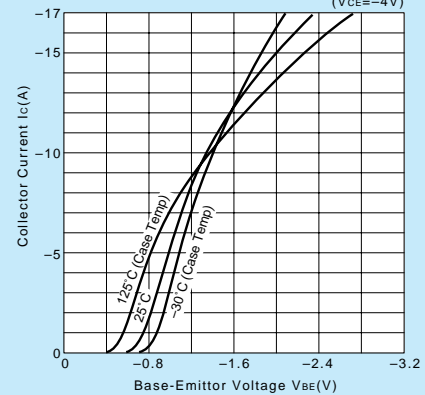
I_C-V_{CE} Characteristics (Typical)



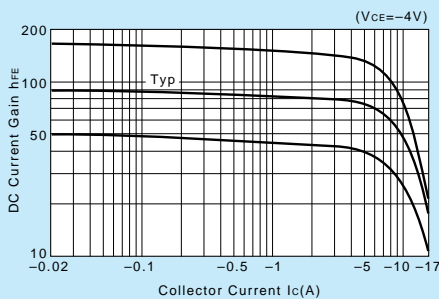
V_{CE(sat)}-I_B Characteristics (Typical)



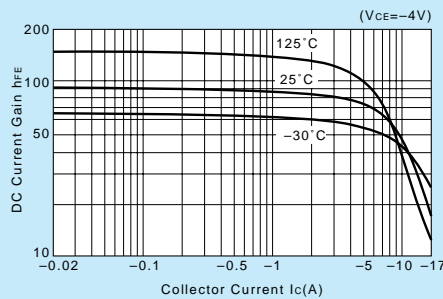
I_C-V_{BE} Temperature Characteristics (Typical)



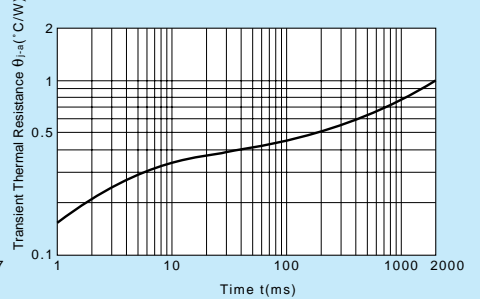
h_{FE}-I_C Characteristics (Typical)



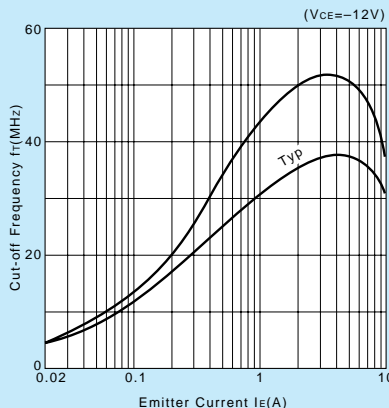
h_{FE}-I_C Temperature Characteristics (Typical)



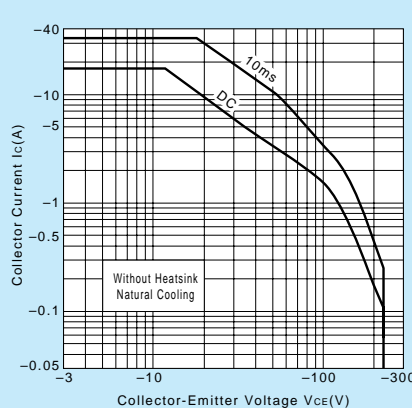
θ_{J-a}-t Characteristics



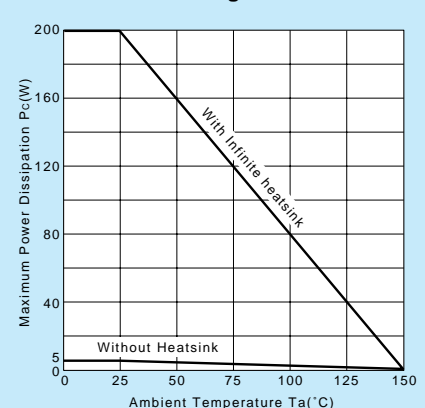
f_T-I_E Characteristics (Typical)



Safe Operating Area (Single Pulse)



P_C-T_a Derating



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